

DS14C238

Single Supply TIA/EIA-232 4 x 4 Driver/Receiver

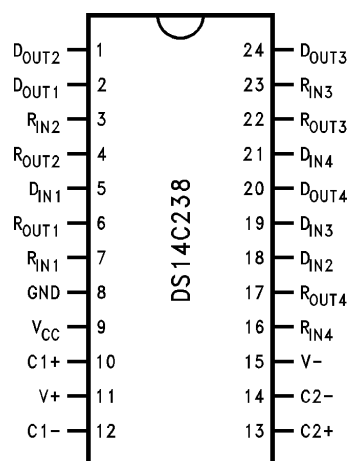
General Description

The DS14C238 is a four driver, four receiver device which conforms to the TIA/EIA-232-E standard and CCITT V.28 recommendations. This device eliminates $\pm 12V$ supplies by employing an internal DC-DC converter to generate the necessary output levels from a single +5V supply. Driver slew rate control and receiver noise filtering have also been internalized to eliminate the need for external slew rate control and noise filtering capacitors.

Features

- Conforms to TIA/EIA-232-E and CCITT V.28
- Internal DC-DC converter
- Operates with single +5V supply
- Low power requirement— I_{CC} 10 mA max
- Internal driver slew rate control
- Receiver noise filtering
- Operates above 120 kbits/sec
- Direct replacement for MAX238

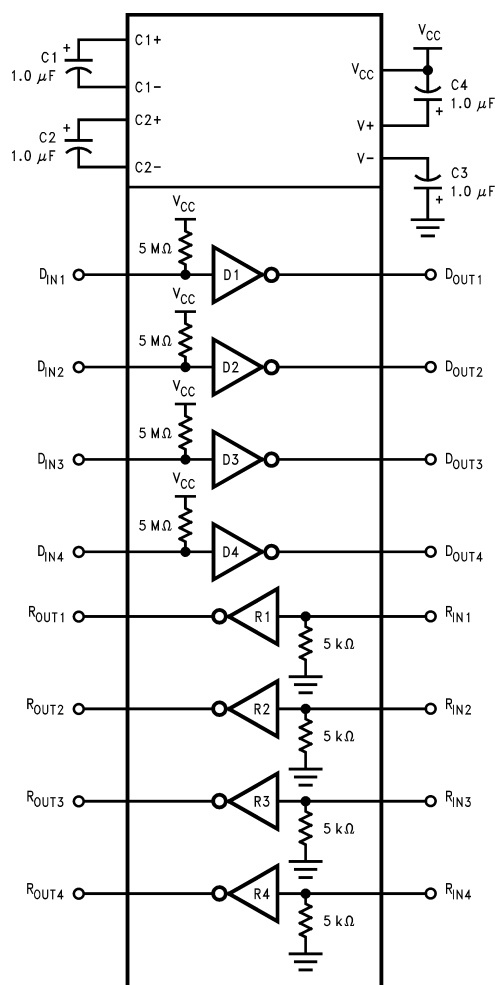
Connection Diagram



01128201

Order Number DS14C238WM, DS14C238WMX
See NS Package Number M24B

Functional Diagram



01128202

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	-0.3V to +6V
V+ Pin	(V_{CC} -0.3V) to +15V
V- Pin	+0.3V to -15V
Driver Input Voltage	-0.3V to (V_{CC} +0.3V)
Driver Output Voltage	(V+ +0.3V) to (V- -0.3V)
Receiver Input Voltage	±30V
Receiver Output Voltage	-0.3V to (V_{CC} +0.3V)
Junction Temperature	+150°C
Maximum Package Power Dissipation @ +25°C (Note 6)	
WM Package	1400 mW

Storage Temp. Range	-65°C to +150°C
Lead Temp.	
(Soldering, 4 Seconds)	+260°C
Short Circuit Duration (D_{OUT})	Continuous
ESD Rating	
(HBM, 1.5 k Ω , 100 pF)	≥ 2.0 kV

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage, V_{CC}	4.5	5.5	V
Operating Free Air Temp. (T_A)			
DS14C238	0	+70	°C

Electrical Characteristics (Note 2)

Over recommended operating conditions, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Units
DEVICE CHARACTERISTICS							
V+	Positive Power Supply	R _L = 3 kΩ, C1–C4 = 1.0 μF, D _{IN} = 0.8V			9.0		V
V–	Negative Power Supply	R _L = 3 kΩ, C1–C4 = 1.0 μF, D _{IN} = 2.0V			–8.0		V
I _{CC}	Supply Current (V _{CC})	No Load			7.0	10	mA
DRIVER CHARACTERISTICS							
V _{IH}	High Level Input Voltage			2.0		V _{CC}	V
V _{IL}	Low Level Input Voltage			GND		0.8	V
I _{IH}	High Level Input Current	V _{IN} ≥ 2.0V		–10		+10	μA
I _{IL}	Low Level Input Current	V _{IN} ≤ 0.8V		–10		+10	μA
V _{OH}	High Level Output Voltage	R _L = 3 kΩ		5.0	7.4		V
V _{OL}	Low Level Output Voltage				–6.3	–5.0	V
I _{OS} ⁺	Output High Short Circuit Current	V _O = 0V, V _{IN} = 0.8V	(Note 3)	–30	–15	–5.0	mA
I _{OS} [–]	Output Low Short Circuit Current	V _O = 0V, V _{IN} = 2.0V		5.0	12	30	mA
R _O	Output Resistance	–2V ≤ V _O ≤ +2V, V _{CC} = GND = 0V		300			Ω
RECEIVER CHARACTERISTICS							
V _{TH}	Input High Threshold Voltage				1.9	2.4	V
V _{TL}	Input Low Threshold Voltage			0.8	1.5		V
V _{HY}	Hysteresis			0.2	0.4	1.0	V
R _{IN}	Input Resistance			3.0	4.5	7.0	kΩ
I _{IN}	Input Current	V _{IN} = +15V		2.14	3.8	5.0	mA
		V _{IN} = +3V		0.43	0.6	+1.0	mA
		V _{IN} = –3V		–1.0	–0.6	–0.43	mA
		V _{IN} = –15V		–5.0	–3.8	–2.14	mA
V _{OH}	High Level Output Voltage	V _{IN} = –3V, I _O = –3.2 mA		3.5	4.5		V
		V _{IN} = –3V, I _O = –20 μA		4.0	4.9		V
V _{OL}	Low Level Output Voltage	V _{IN} = +3V, I _O = +2.0 mA			0.25	0.4	V

Switching Characteristics (Note 4)

Over recommended operating conditions, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
DRIVER CHARACTERISTICS						
t_{PLH}	Propagation Delay LOW to HIGH	$R_L = 3\text{ k}\Omega$ $C_L = 50\text{ pF}$ (Figures 1, 2)		0.7	4.0	μs
t_{PHL}	Propagation Delay HIGH to LOW			0.6	4.0	μs
t_{sk}	Skew $ t_{PLH} - t_{PHL} $			0.1	1.0	μs
SR1	Output Slew Rate	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$, $C_L = 50\text{ pF}$	4.0	15	30	$\text{V}/\mu\text{s}$
SR2	Output Slew Rate	$R_L = 3\text{ k}\Omega$, $C_L = 2500\text{ pF}$	3.0	5.0		$\text{V}/\mu\text{s}$
RECEIVER CHARACTERISTICS						
t_{PLH}	Propagation Delay LOW to HIGH	Input Pulse Width $> 10\text{ }\mu\text{s}$ $C_L = 50\text{ pF}$		2.0	6.5	μs
t_{PHL}	Propagation Delay HIGH to LOW			2.8	6.5	μs
t_{sk}	Skew $ t_{PLH} - t_{PHL} $	(Figures 3, 4)		0.8	2.0	μs
t_{NW}	Noise Pulse Width Rejected	(Figures 3, 4)		2.5	1.0	μs

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground unless otherwise specified.

Note 3: I_{OS+} and I_{OS-} values are for one output at a time. If more than one output is shorted simultaneously, the device power dissipation may be exceeded.

Note 4: Receiver AC input waveform for test purposes: $t_r = t_f = 200\text{ ns}$, $V_{IH} = 3\text{V}$, $V_{IL} = -3\text{V}$, $f = 64\text{ kHz}$ (128 kbits/sec). Driver AC input waveform for test purposes: $t_r = t_f \leq 10\text{ ns}$, $V_{IH} = 3\text{V}$, $V_{IL} = 0\text{V}$, $f = 64\text{ kHz}$ (128 kbits/sec).

Note 5: All typicals are given for $V_{CC} = 5.0\text{V}$ and $T_A = +25^\circ\text{C}$.

Note 6: Ratings apply to ambient temperature at $+25^\circ\text{C}$. Above this temperature derate: WM package $13.5\text{ mW}/^\circ\text{C}$.

Parameter Measurement Information

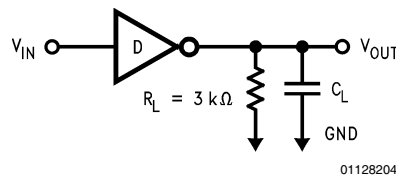


FIGURE 1. Driver Load Circuit

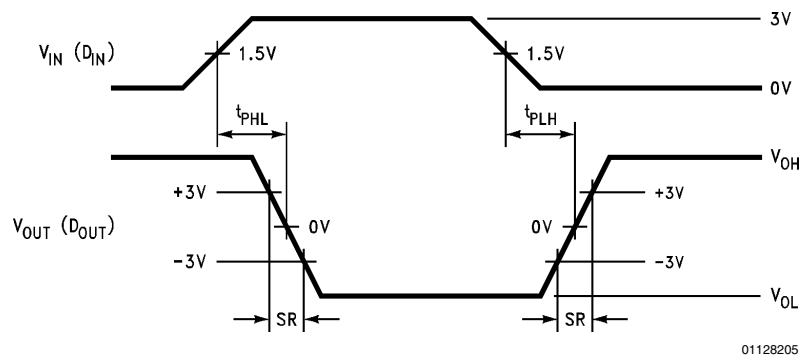


FIGURE 2. Driver Switching Waveform

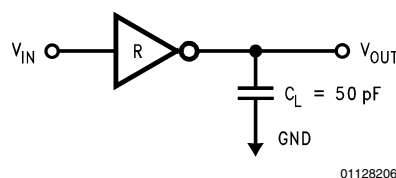


FIGURE 3. Receiver Load Circuit

Parameter Measurement Information (Continued)

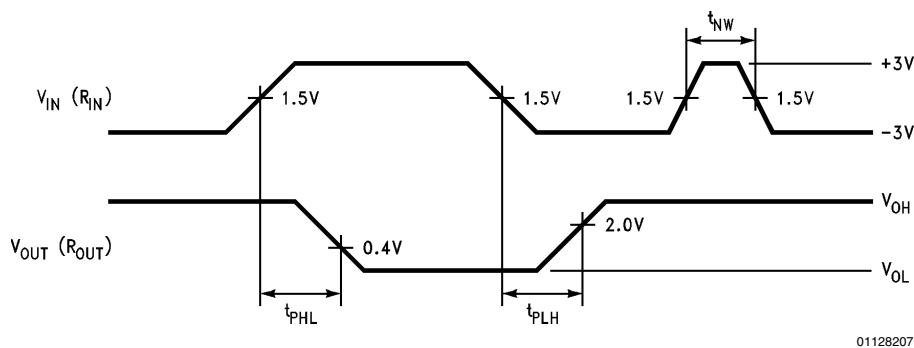


FIGURE 4. Receiver Propagation Delays and Noise Rejection

Pin Descriptions

V_{CC} (pin 9)— Power supply pin for the device, +5V ($\pm 10\%$).

V+ (pin 11)— Positive supply for TIA/EIA-232-E drivers. Recommended external capacitor: C4 = 1.0 μ F (6.3V). This supply is not intended to be loaded externally.

V- (pin 15)— Negative supply for TIA/EIA-232-E drivers. Recommended external capacitor: C3 = 1.0 μ F (16V). This supply is not intended to be loaded externally.

C1+, C1- (pins 10 and 12)— External capacitor connection pins. Recommended capacitor – 1.0 μ F (6.3V).

C2+, C2- (pins 13 and 14)— External Capacitor connection pins. Recommended capacitor – 1.0 μ F (16V).

D_{IN} 1–4 (pins 5, 18, 19, and 21)— Driver input pins are TTL/CMOS compatible. Inputs of unused drivers may be left open, an internal pull-up resistor (500 k Ω minimum, typically 5 M Ω) pulls input to V_{CC}. Output will be LOW for open inputs.

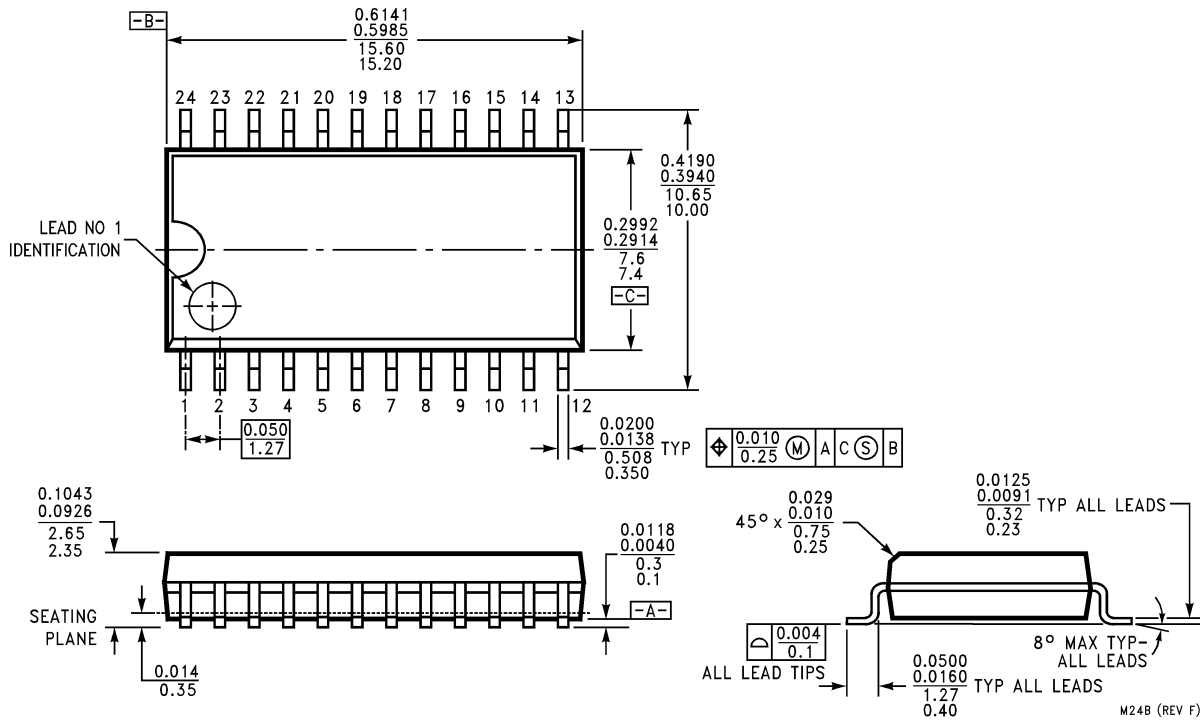
D_{OUT} 1–4 (pins 2, 1, 24, and 20)— Driver output pins conform to TIA/EIA-232-E levels.

R_{IN1} 1–4 (pins 3, 7, 23, and 16)— Receiver input pins accept TIA/EIA-232-E input voltages (± 15 V). Receivers feature a noise filter and guaranteed hysteresis of 200 mV. Unused receiver input pins may be left open. Internal input resistor (5 k Ω) pulls input LOW, providing a failsafe HIGH output.

R_{OUT} 1–4 (pins 4, 6, 22, and 17)— Receiver output pins are TTL/CMOS compatible. Receiver output HIGH voltage is specified for both CMOS and TTL load conditions.

GND (pin 8)— Ground Pin.

Physical Dimensions inches (millimeters) unless otherwise noted



LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Corporation
Americas
Email: support@nsc.com

www.national.com

National Semiconductor Europe

Fax: +49 (0) 180-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 69 9508 6208
English Tel: +44 (0) 870 24 0 2171
Français Tel: +33 (0) 1 41 91 8790

National Semiconductor Asia Pacific Customer Response Group

Tel: 65-2544466
Fax: 65-2504466
Email: ap.support@nsc.com

National Semiconductor Japan Ltd.

Tel: 81-3-5639-7560
Fax: 81-3-5639-7507



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.